	Application No.	Applicant(s)
	09/772,457	NAKAMURA ET AL.
Notice of Allowability	Examiner	Art Unit
	William T. Leader	1742
The MAILING DATE of this communication app All claims being allowable, PROSECUTION ON THE MERITS Is herewith (or previously mailed), a Notice of Allowance (PTOL-85 NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT Is of the Office or upon petition by the applicant. See 37 CFR 1.31	S (OR REMAINS) CLOSED in 5) or other appropriate commune RIGHTS. This application is su	this application. If not included nication will be mailed in due course. THIS
1. X This communication is responsive to the papers filed 17 l	December 2003.	
2. $igtimes$ The allowed claim(s) is/are <u>1-6 and 9</u> .		
3. $igotimes$ The drawings filed on 30 January 2001 are accepted by t	he Examiner.	
4. Acknowledgment is made of a claim for foreign priority of a) All b) Some* c) None of the: 1. Certified copies of the priority documents have 2. Certified copies of the priority documents have 3. Copies of the certified copies of the priority of International Bureau (PCT Rule 17.2(a)). * Certified copies not received: Applicant has THREE MONTHS FROM THE "MAILING DATE noted below. Failure to timely comply will result in ABANDON THIS THREE-MONTH PERIOD IS NOT EXTENDABLE. 5. A SUBSTITUTE OATH OR DECLARATION must be sub INFORMAL PATENT APPLICATION (PTO-152) which gi 6. CORRECTED DRAWINGS (as "replacement sheets") mice (a) including changes required by the Notice of Draftspee 1) hereto or 2) to Paper No./Mail Date (b) including changes required by the attached Examine Paper No./Mail Date Identifying indicia such as the application number (see 37 CFR each sheet. Replacement sheet(s) should be labeled as such in 7. DEPOSIT OF and/or INFORMATION about the departached Examiner's comment regarding REQUIREMENT	ve been received. ve been received in Application ocuments have been received "" of this communication to file MENT of this application. mitted. Note the attached EXA ves reason(s) why the oath or ust be submitted. rson's Patent Drawing Review r's Amendment / Comment or 1.84(c)) should be written on the the header according to 37 CFR cosit of BIOLOGICAL MATE	in No in this national stage application from the a reply complying with the requirements MINER'S AMENDMENT or NOTICE OF declaration is deficient. (PTO-948) attached in the Office action of e drawings in the front (not the back) of R 1.121(d). ERIAL must be submitted. Note the
Attachment(s) 1. ☐ Notice of References Cited (PTO-892) 2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948) 3. ☐ Information Disclosure Statements (PTO-1449 or PTO/SB Paper No./Mail Date) 6. ⊠ Interview Su Paper No./I √08), 7. ⊠ Examiner's	ormal Patent Application (PTO-152) Immary (PTO-413), Mail Date <u>20040129</u> Amendment/Comment Statement of Reasons for Allowance

Art Unit: 1742

EXAMINER'S AMENDMENT

An examiner's amendment to the record appears below. Should the changes

and/or additions be unacceptable to applicant, an amendment may be filed as

provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST

be submitted no later than the payment of the issue fee.

Authorization for this examiner's amendment was given in a telephone

interview with Derek S. Jessen on February 6, 2004.

The application has been amended as follows:

In the Claims:

Claim 1 has been rewritten as follows:

A method of plating for filling via holes, in which each of via holes formed in

an insulation layer covering a substrate so as to expose, at its bottom, part of a

conductor layer located on the substrate, is plated with copper to [be filled with the

plated metall fill the via holes with plated copper, the method comprising the steps

of:

1.

forming a copper film on the top surface of the insulation layer covering the

substrate, and the side walls and bottoms of the respective via holes,

[providing] forming a strike plating of copper on the surface of the copper

film,

Art Unit: 1742

immersing the substrate having the copper film <u>and copper strike plating</u> formed <u>thereon</u> in an aqueous solution containing a plating promoter to thereby deposit the plating promoter on the surface of the copper [film] <u>strike plating</u>,

removing the plating promoter from the surface of the copper [film] strike plating located on the top surface of the insulation layer and leaving the plating promoter on the side walls and bottoms of the respective via holes, and

electroplating the substrate having the copper film [formed] and copper strike plating with copper to thereby fill the via holes with the plated copper and simultaneously form a continuous copper film which eventually covers the via holes filled with the plated copper as well as the copper [film] strike plating previously formed on the top surface of the insulation layer.

Claim 6 has been rewritten as follows:

6. The method of claim 1, wherein the plating promoter is removed by a process or treatment selected from the group consisting of (1) an etching process using an etching solution for copper, (2) a cyanide electrolytic treatment using a cyanide electrolytic bath, (3) an ultraviolet radiation treatment obliquely irradiating the surface of the copper [film] strike plating on the insulation layer with ultraviolet radiation, and (4) a treatment of polishing the surface of the copper [film] strike plating on the top of the insulation layer.

Art Unit: 1742

Claims 7, 8 and 10 have canceled.

In the Abstract:

The abstract has been rewritten as shown on the attached sheet.

COMMENTS

Claim 1 has been amended to clarify the wording of the claim. In the amendment filed on November 17, 2003, applicant added the limitation of claim 11, "providing a strike plating of copper on the surface of the copper film", to claim 1 before the step of depositing the plating promoter. As explained at page 13, lines 14-27 of the specification, the plating promoter can be evenly and uniformly deposited on the clean surface provided by the copper strike plating. Thus, rather than being formed on the first copper film as previously recited in claim 1, the plating promoter is deposited on the copper strike plating. Claim 1 has been amended to be consistent with the limitation added in the November 17 amendment by indicating that the plating promoter is deposited on the copper strike plating. Claims 7, 8 and 10 have been canceled as being directed to non-elected species. The abstract has been shortened to less than 150 words as required by MPEP 608.01(b).

Art Unit: 1742

As noted by applicant at page 5 of the Remarks, the wording of the reasons for allowance of claim 11 as written in the previous office action was incorrect. The correct statement is as follows: the prior art of record does not suggest forming a strike plating of copper on the surface of the initial copper film formed in the process of claim 1 prior to the immersion of the substrate in the plating promoter-containing solution.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Any inquiry concerning this communication or earlier communications from the examiner should be directed to William Leader whose telephone number is 571-272-1245. The examiner can normally be reached Mondays through Thursdays from 8:00 to 4:30 and every other Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Roy King, can be reached at telephone number 571-272-1244. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Art Unit: 1742

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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William Leader February 6, 2004

Art Unit: 1742

Abstract

A method of plating for filling via holes, in which each via hole is formed in an insulation layer covering a substrate so as to expose, at its bottom, part of a conductor layer located on the substrate. [, is plated with copper, to be filled with the plated metal, the method comprising the steps of forming a] A copper film is formed on the top surface of the insulation layer covering the substrate, and the side walls and bottoms of the respective via holes. [, immersing the substrate having the copper film formed] A strike plating of copper is provided on the copper film, and the substrate is immersed in an aqueous solution containing a plating promoter to thereby deposit the plating promoter on the surface of the copper [film,] strike. [removing the] The plating promoter is removed from [the surface of] the copper [film] strike plating located on the top <u>surface</u> insulation layer [and] <u>while</u> leaving the plating promoter on the side walls and bottoms of the respective via holes. [, and] The substrate is subsequently electroplated with copper to fill the via holes. [electroplating the substrate having the copper film formed with copper to thereby fill the via holes with the plated copper and simultaneously form a continuous copper film which eventually covers the via holes filled with the plated copper as well as the copper film previously formed on the insulation layer. The method is suitable for satisfactorily filling via holes, having a small diameter and a large aspect ratio, with plated copper.]